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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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N-Channel Power MOSFET

60V, 3A, 85mΩ

FEATURES

- Low R_{DS(ON)} to minimize conductive losses
- Logic level
- Low gate charge for fast power switching
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V _D	S	60	٧	
D (****)	$V_{GS} = 10V$	85	0	
$R_{DS(on)}$ (max)	$V_{GS} = 4.5V$	100	mΩ	
Q	9	4.6	nC	

Pb

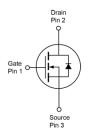




APPLICATIONS

- BLDC Motor Control
- Battery Power Management
- LED backlight





Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current (Note 1)	$T_C = 25^{\circ}C$		3	Α	
Continuous Drain Current	$T_A = 25^{\circ}C$	l _D	2.3		
Pulsed Drain Current		I _{DM}	12	Α	
Total Dawar Dissination	$T_C = 25^{\circ}C$	D	1.7	W	
Total Power Dissipation	$\frac{T_{C} = 25^{\circ}C}{T_{C} = 125^{\circ}C}$ P _D	P _D	0.3	۷V	
Total Davier Dissination	$T_A = 25^{\circ}C$	D	1	W	
Total Power Dissipation	$T_A = 125$ °C	P _D	0.2		
Operating Junction and Storage Temp	erature Range	T_{J}, T_{STG}	- 55 to +150	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	75	°C/W	
Junction to Ambient Thermal Resistance	R _{eJA}	124	°C/W	

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

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PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						•
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	60			V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	$V_{GS(TH)}$	1.2	1.8	2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0 V$	I _{GSS}			±100	nA
	$V_{GS} = 0V, V_{DS} = 60V$				1	μΑ
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 60V$ $T_{J} = 125^{\circ}C$	I _{DSS}			100	
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 2.3A$	_		68	85	mΩ
(Note 2)	$V_{GS} = 4.5V, I_D = 2.3A$	$R_{DS(on)}$		80	100	
Forward Transconductance (Note 2)	$V_{DS} = 5V, I_{D} = 2.3A$	g _{fs}		6.7		S
Dynamic (Note 3)						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 30V,$ $I_{D} = 2.3A$	Q_g		9.5		
Total Gate Charge	$V_{GS} = 4.5V, V_{DS} = 30V,$	Q_g		4.6		nC
Gate-Source Charge		Q_{gs}		1.9		1
Gate-Drain Charge	$I_D = 2.3A$	Q_{gd}		1.6		
Input Capacitance		C _{iss}		529		
Output Capacitance	$V_{GS} = 0V, V_{DS} = 30V$	C _{oss}		29		рF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		3		
Gate Resistance	f = 1.0MHz, open drain	R_g		1.5		Ω
Switching (Note 3)						
Turn-On Delay Time		t _{d(on)}		4.8		
Turn-On Rise Time	$V_{GS} = 10V, V_{DS} = 30V,$ $I_D = 2.3A, R_G = 2\Omega$	t _r		20		
Turn-Off Delay Time		t _{d(off)}		9.8		ns
Turn-Off Fall Time		t _f		17		
Source-Drain Diode						
Forward Voltage (Note 2)	$V_{GS} = 0V, I_{S} = 2.3A$	V_{SD}			1	٧
Reverse Recovery Time	I _S = 2.3A,	t _{rr}		12		ns
Reverse Recovery Charge	dl/dt = 100A/µs	Q _{rr}		8		nC

Notes:

- 1. Silicon limited current only.
- 2. Pulse test: Pulse Width ≤ 300µs, duty cycle ≤ 2%.
- 3. Switching time is essentially independent of operating temperature.

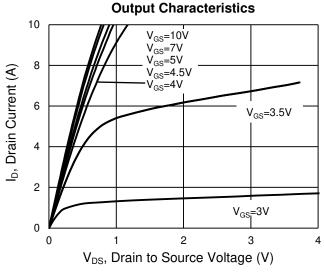
ORDERING INFORMATION

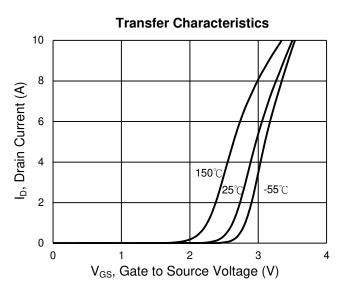
PART NO.	PACKAGE	PACKING
TSM850N06CX RFG	SOT-23	3,000pcs / 7" Reel

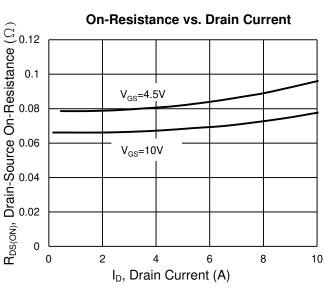


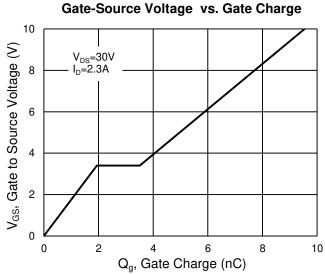
CHARACTERISTICS CURVES

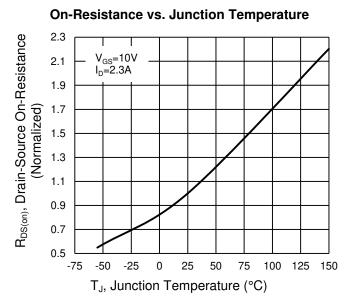
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

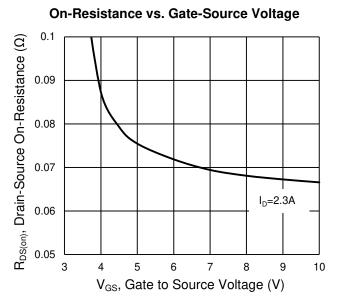












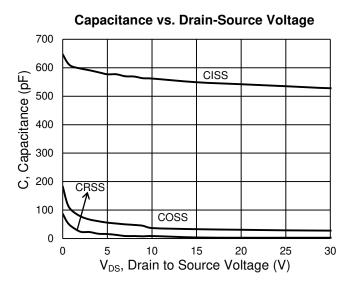
Version: B1607

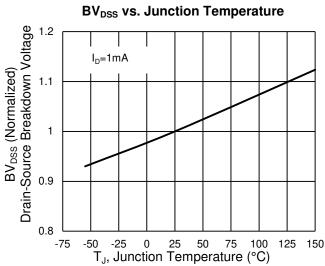
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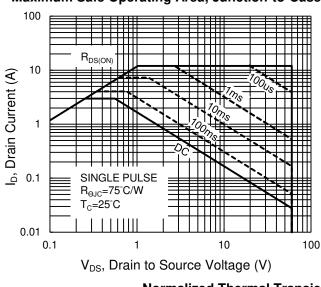
CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

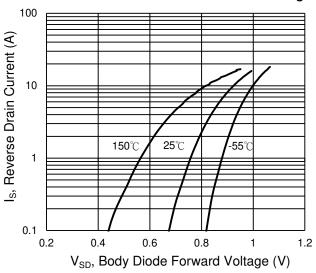




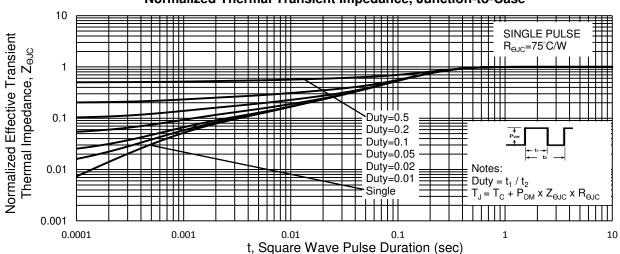
Maximum Safe Operating Area, Junction-to-Case







Normalized Thermal Transient Impedance, Junction-to-Case

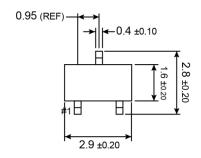


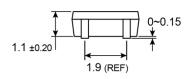
4

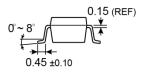


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

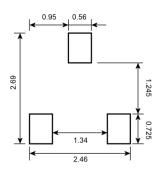
SOT-23







SUGGESTED PAD LAYOUT (Unit: Millimeters)



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MARKING DIAGRAM



85 = Device Code

Y = Year Code

M = Month Code

O =Jan P =Feb Q =Mar R =Apr

 $\label{eq:Sample_S} \textbf{S} \ = \!\!\! \text{May} \quad \textbf{T} \ = \!\!\! \text{Jun} \quad \textbf{U} \ = \!\!\! \text{Jul} \quad \textbf{V} \ = \!\!\! \text{Aug}$

W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code



Taiwan Semiconductor

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